

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LCX16244FT

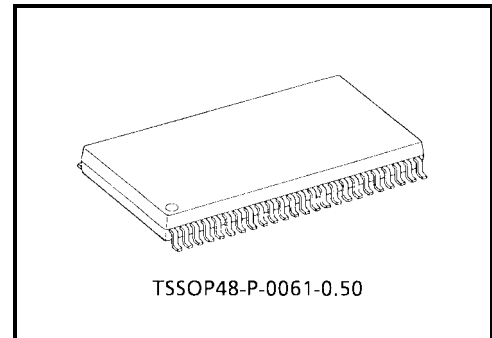
## Low-Voltage 16-Bit Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX16244FT is a high-performance CMOS 16-bit bus buffer. Designed for use in 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (2.5-V or 3.3-V)  $V_{CC}$  applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

This device is non-inverting 3-state buffer having four active-low output enables. It can be used as four 4-bit buffers two 8-bit buffers or one 16-bit buffer. When the  $\overline{OE}$  input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

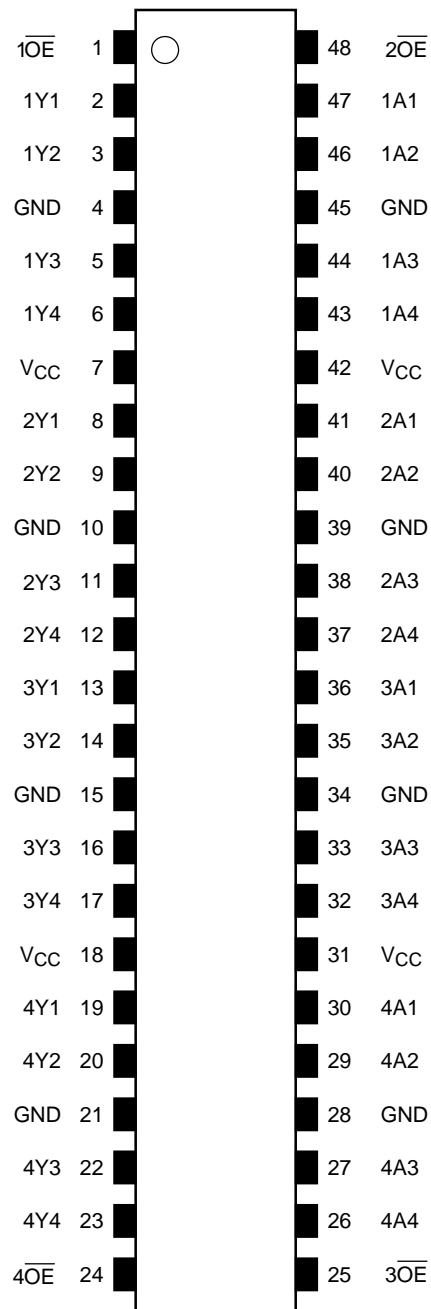


Weight: 0.25 g (typ.)

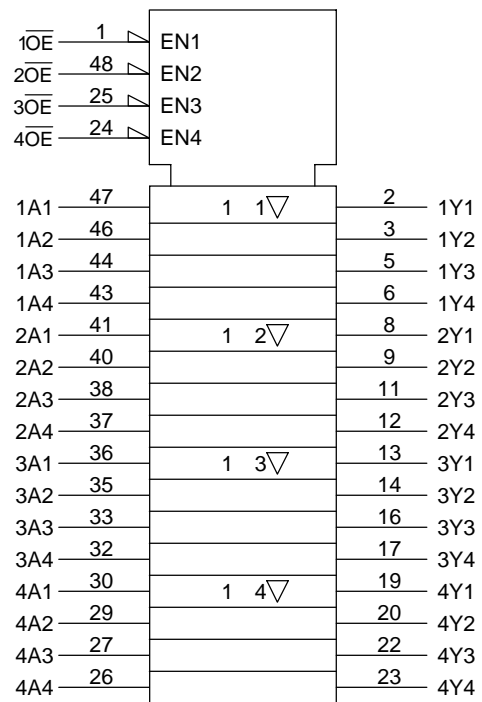
### Features

- Low-voltage operation:  $V_{CC} = 2.0$  to  $3.6$  V
- High-speed operation:  $t_{pd} = 4.5$  ns (max) ( $V_{CC} = 3.0$  to  $3.6$  V)
- Output current:  $|I_{OH}|/I_{OL} = 24$  mA (min) ( $V_{CC} = 3.0$  V)
- Latch-up performance:  $\pm 500$  mA
- Package: TSSOP (thin shrink small outline package)
- Power-down protection provided on all inputs and outputs

## Pin Assignment (top view)



## IEC Logic Symbol



## Truth Table

Inputs		Outputs
$\overline{1OE}$	1A1-1A4	1Y1-1Y4
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{2OE}$	2A1-2A4	2Y1-2Y4
L	L	L
L	H	H
H	X	Z

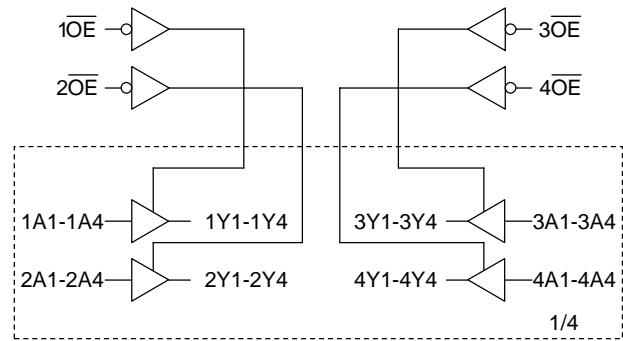
Inputs		Outputs
$\overline{3OE}$	3A1-3A4	3Y1-3Y4
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$\overline{4OE}$	4A1-4A4	4Y1-4Y4
L	L	L
L	H	H
H	X	Z

X: Don't care

Z: High impedance

## System Diagram



## Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	-0.5 to 6.0	V
Input voltage	$V_{IN}$	-0.5 to 7.0	V
Output voltage	$V_{OUT}$	-0.5 to 7.0 (Note 1)	V
		-0.5 to $V_{CC} + 0.5$ (Note 2)	
Input diode current	$I_{IK}$	-50	mA
Output diode current	$I_{OK}$	$\pm 50$ (Note 3)	mA
DC output current	$I_{OUT}$	$\pm 50$	mA
Power dissipation	$P_D$	400	mW
DC $V_{CC}$ /ground current per supply pin	$I_{CC}/I_{GND}$	$\pm 100$	mA
Storage temperature	$T_{stg}$	-65 to 150	°C

Note 1: Output in OFF state

Note 2: High or low state.  $I_{OUT}$  absolute maximum rating must be observed.

Note 3:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

## Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	2.0 to 3.6	V
		1.5 to 3.6 (Note 4)	
Input voltage	$V_{IN}$	0 to 5.5	V
Output voltage	$V_{OUT}$	0 to 5.5 (Note 5)	V
		0 to $V_{CC}$ (Note 6)	
Output current	$I_{OH}/I_{OL}$	$\pm 24$ (Note 7)	mA
		$\pm 12$ (Note 8)	
		$\pm 8$ (Note 9)	
Operating temperature	$T_{opr}$	-40 to 85	°C
Input rise and fall time	$dt/dv$	0 to 10 (Note 10)	ns/V

Note 4: Data retention only

Note 5: Output in OFF state

Note 6: High or low state

Note 7:  $V_{CC} = 3.0$  to  $3.6$  V

Note 8:  $V_{CC} = 2.7$  to  $3.0$  V

Note 9:  $V_{CC} = 2.3$  to  $2.7$  V

Note 10:  $V_{IN} = 0.8$  to  $2.0$  V,  $V_{CC} = 3.0$  V

**Electrical Characteristics**

**DC Characteristics (Ta = -40 to 85°C)**

Characteristics		Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit	
Input voltage	H-level	V <sub>IH</sub>	—		2.3 to 2.7	1.7	—	V	
					2.7 to 3.6	2.0	—		
	L-level	V <sub>IL</sub>			2.3 to 2.7	—	0.7		
					2.7 to 3.6	—	0.8		
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		I <sub>OH</sub> = -100 μA	2.3 to 3.6	V <sub>CC</sub> - 0.2	—	V
					I <sub>OH</sub> = -8 mA	2.3	1.8	—	
					I <sub>OH</sub> = -12 mA	2.7	2.2	—	
					I <sub>OH</sub> = -18 mA	3.0	2.4	—	
					I <sub>OH</sub> = -24 mA	3.0	2.2	—	
	L-level	V <sub>OL</sub>			I <sub>OL</sub> = 100 μA	2.3 to 3.6	—	0.2	
					I <sub>OL</sub> = 8 mA	2.3	—	0.6	
					I <sub>OL</sub> = 12 mA	2.7	—	0.4	
					I <sub>OL</sub> = 16 mA	3.0	—	0.4	
					I <sub>OL</sub> = 24 mA	3.0	—	0.55	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		2.3 to 3.6	—	±5.0	μA	
3-state output off-state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 5.5 V		2.3 to 3.6	—	±5.0	μA	
Power off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0	—	10.0	μA	
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.3 to 3.6	—	20.0	μA	
			V <sub>IN</sub> /V <sub>OUT</sub> = 3.6 to 5.5 V		2.3 to 3.6	—	±20.0		
Increase in I <sub>CC</sub> per input		ΔI <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V		2.3 to 3.6	—	500		

**AC Characteristics (Ta = -40 to 85°C)**

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2		2.5 ± 0.2	30	1.5	5.4	ns
	t <sub>pHL</sub>			2.7	50	1.5	5.2	
				3.3 ± 0.3	50	1.5	4.5	
3-state output enable time	t <sub>pZL</sub>	Figure 1, Figure 3		2.5 ± 0.2	30	1.5	7.2	ns
	t <sub>pZH</sub>			2.7	50	1.5	6.3	
				3.3 ± 0.3	50	1.5	5.5	
3-state output disable time	t <sub>pLZ</sub>	Figure 1, Figure 3		2.5 ± 0.2	30	1.5	6.5	ns
	t <sub>pHZ</sub>			2.7	50	1.5	5.7	
				3.3 ± 0.3	50	1.5	5.4	
Output to output skew	t <sub>osLH</sub>	(Note 11)		2.5 ± 0.2	30	—	—	ns
	t <sub>osHL</sub>			2.7	50	—	—	
				3.3 ± 0.3	50	—	1.0	

Note 11: Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

## Dynamic Switching Characteristics ( $T_a = 25^\circ\text{C}$ , input: $t_r = t_f = 2.5 \text{ ns}$ , $R_L = 500 \Omega$ )

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Typ.	Unit
			Quiet output maximum dynamic		
			3.3	0.8	
Quiet output minimum dynamic	$V_{OL}$	$ V_{OLV} $	2.5	0.6	V
			3.3	0.8	

## Capacitive Characteristics ( $T_a = 25^\circ\text{C}$ )

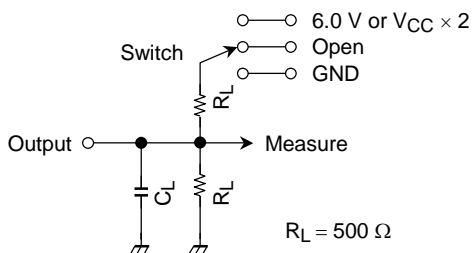
Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Typ.	Unit
			Input capacitance		
Output capacitance	$C_{OUT}$	—	3.3	8	pF
Power dissipation capacitance	$C_{PD}$	$f_{IN} = 10 \text{ MHz}$ (Note 12)	3.3	25	pF

Note 12:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$$

## AC Test Circuit



Parameter	Switch
$t_{pLH}$ , $t_{pHL}$	Open
$t_{pLZ}$ , $t_{pZL}$	6.0 V @ $V_{CC} = 3.3 \pm 0.3 \text{ V}$ $V_{CC} \times 2$ @ $V_{CC} = 2.5 \pm 0.2 \text{ V}$
$t_{pHZ}$ , $t_{pZH}$	GND

Figure 1

## AC Waveform

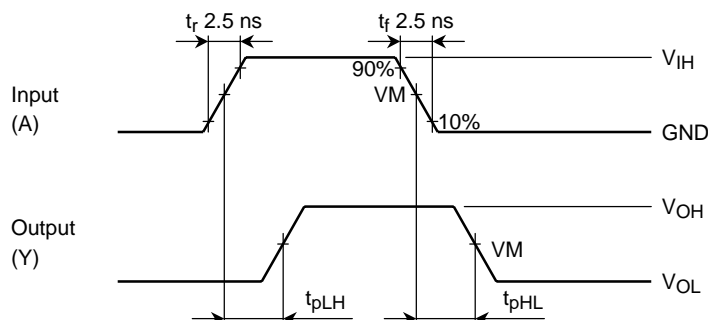
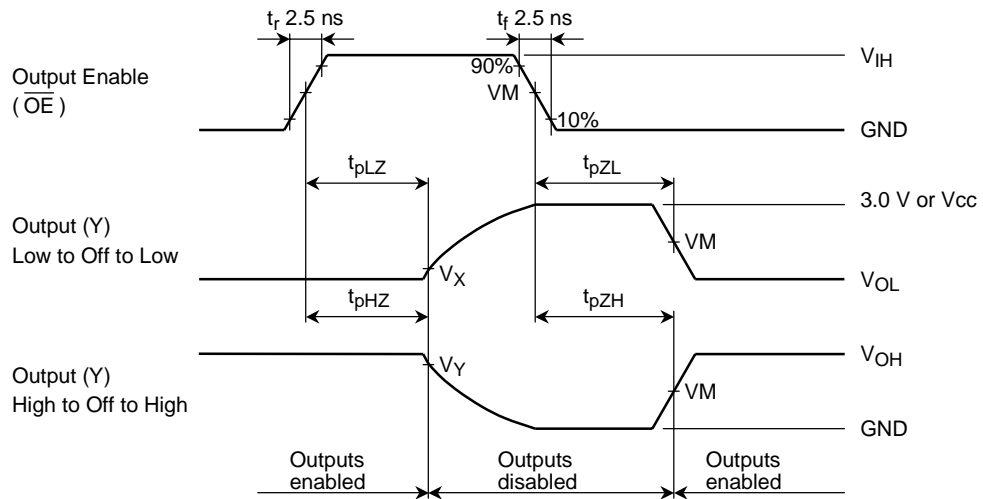


Figure 2  $t_{pLH}$ ,  $t_{pHL}$



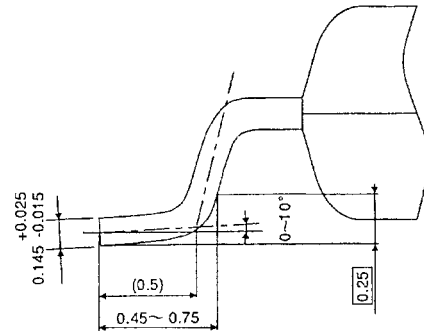
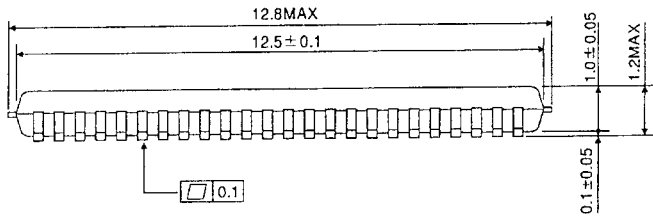
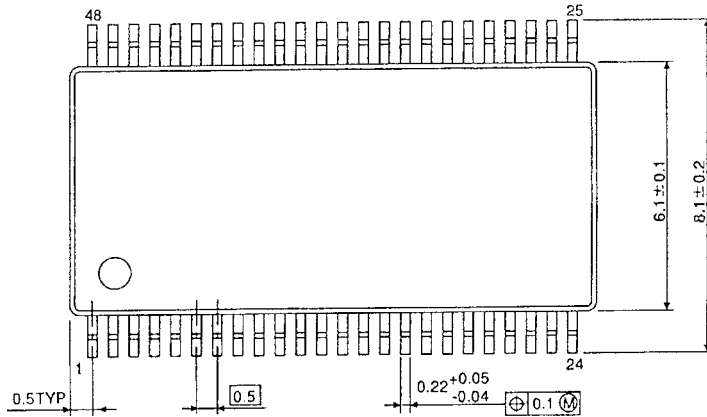
**Figure 3**  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$

Symbol	$V_{CC}$		
	$3.3 \pm 0.3 \text{ V}$	$2.7 \text{ V}$	$2.5 \pm 0.2 \text{ V}$
$V_{IH}$	$2.7 \text{ V}$	$2.7 \text{ V}$	$V_{CC}$
$V_M$	$1.5 \text{ V}$	$1.5 \text{ V}$	$V_{CC}/2$
$V_X$	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.15 \text{ V}$
$V_Y$	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.15 \text{ V}$

**Package Dimensions**

TSSOP48-P-0061-0.50

Unit : mm



Weight: 0.25 g (typ.)



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